

# isc N-Channel MOSFET Transistor

## RD3P175SN

## FEATURES

- Drain Current –I\_D= 17.5A@ T\_C=25 $^\circ\!\!\mathbb{C}$
- Drain Source Voltage-: V<sub>DSS</sub>= 100V(Min)
- Static Drain-Source On-Resistance
- : R<sub>DS(on)</sub> = 105m Ω (Max)
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

#### DESCRIPTION

• Designed for use in switch mode power supplies and general purpose applications.

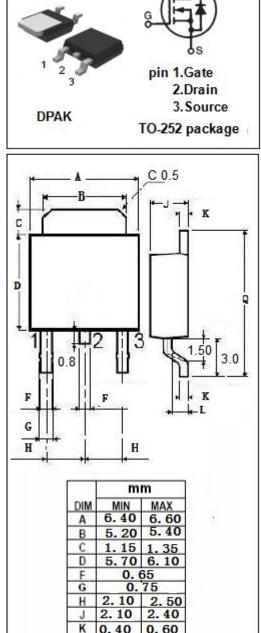
ADSOLUTE WAATINUW RATINGS(Ta-25 C)						
SYMBOL	PARAMETER VAL		UNIT			
V <sub>DSS</sub>	Drain-Source Voltage	100	V			
V <sub>GS</sub>	Gate-Source Voltage-Continuous	Source Voltage-Continuous ±20				
ID	Drain Current-Continuous	17.5	A			
I <sub>DM</sub>	Drain Current-Single Pluse	35	A			
P <sub>D</sub>	Total Dissipation @T <sub>c</sub> =25℃ 20		W			
TJ	Max. Operating Junction Temperature	150	°C			
T <sub>stg</sub>	Storage Temperature	-55~150	°C			

## ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

**THERMAL CHARACTERISTICS** 

SYMBOL

Rth j-c



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PARAMETER

Thermal Resistance, Junction to Case

MAX

6.25

UNIT

°C/W

0

0.90

9.90



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### **ELECTRICAL CHARACTERISTICS**

#### $T_c=25^{\circ}C$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	МАХ	UNIT
V(BR)DSS	Drain-Source Breakdown Voltage	V <sub>GS</sub> = 0; I <sub>D</sub> = 1mA	100		V
V <sub>GS</sub> (th)	Gate Threshold Voltage	V <sub>DS</sub> = V <sub>GS</sub> ; I <sub>D</sub> = 1mA	1	2.5	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> = 10V; I <sub>D</sub> = 8.8A		105	mΩ
I <sub>GSS</sub>	Gate-Body Leakage Current	V <sub>GS</sub> = ±20V;V <sub>DS</sub> = 0		±10	uA
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> = 100V; V <sub>GS</sub> = 0		1	μA
V <sub>SD</sub>	Forward On-Voltage	I <sub>S</sub> = 17.5A; V <sub>GS</sub> = 0		1.5	V

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